



ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

October 26, 2026	
IGI Report Number	LG852642771
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	SQUARE EMERALD CUT
Measurements	9.73 X 9.49 X 5.99 MM

GRADING RESULTS

Carat Weight	5.07 CARATS
Color Grade	E
Clarity Grade	VVS 2

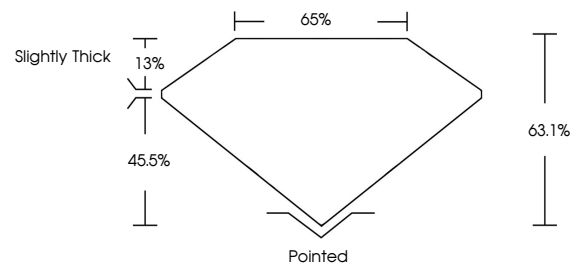
ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	15 LG852642771

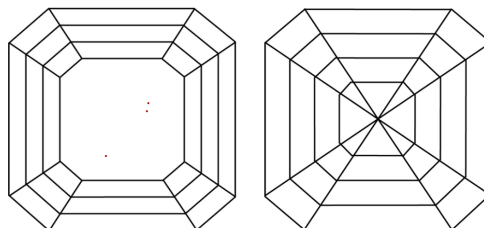
Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.
Type IIa

LG852642771
Report verification at igi.org

PROPORTIONS



CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.



Sample Image Used

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL	IF	VVS ¹⁻²	VS ¹⁻²	SI ¹⁻²	I ¹⁻³
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included

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ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	LG LG85264277
<p>Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.</p> <p>Type IIa</p>	



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www.igi.org

October 26, 2026
 IGI Report No LG855
 SQUARE EMERALD C

5.07 CARATS	Pointed
VVS 2	EXCELLENT
63.1%	EXCELLENT
66%	NONE
Slightly Thick	4mm Carat (0.7771)

Comments:
This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.